

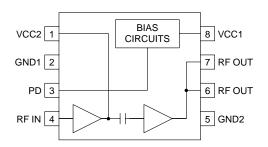
### MEDIUM POWER LINEAR AMPLIFIER

### Typical Applications

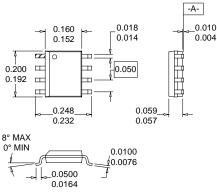
- DECT Cordless Applications
- PCS Communication Systems
- Commercial and Consumer Systems
- Portable Battery-Powered Equipment

### **Product Description**

The RF2127 is a medium-power, high-efficiency, linear amplifier IC. The device is manufactured on an advanced Gallium Arsenide Heterojunction Bipolar Transistor (HBT) process, and has been designed for use as the final RF amplifier in 1800MHz digital PCS phone transmitters requiring linear amplification operating between 1800MHz and 1900MHz, with over 100mW transmitted power. It will also function as the driver stage for the RF2125 high power amplifier. A simple power down function is included for TDD operation.



Functional Block Diagram



#### NOTES:

- 1. Shaded lead is pin 1.
- 2. All dimensions are excluding flash, protrusions or burrs.
- 3. Lead coplanarity: 0.005 with respect to datum "A".
- 4. Package surface finish: Matte (Charmilles #24~27).

Package Style: SOIC-8

### **Features**

- Single 3.0V to 6.5V Supply
- 100mW Linear Output Power
- 25dB Small Signal Gain
- 30% Efficiency
- Digitally Controlled Power Down Mode
- 1500MHz to 1900MHz Operation

### Ordering Information

RF2127 Medium Power Linear Amplifier RF2127 PCBA Fully Assembled Evaluation Board

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 http://www.rfmd.com

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# RF2127

### **Absolute Maximum Ratings**

Parameter	Rating	Unit
Supply Voltage (V <sub>CC</sub> )	-0.5 to +7.5	$V_{DC}$
Power Down Voltage (V <sub>PD</sub> )	-0.5 to +5.5	V
DC Supply Current	125	mA
Input RF Power	+12	dBm
Output Load VSWR	20:1	
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	ů



RF Micro Devices believes the furnished information is correct and accurate at the time of this printing. However, RF Micro Devices reserves the right to make changes to its products without notice. RF Micro Devices does not assume responsibility for the use of the described product(s).

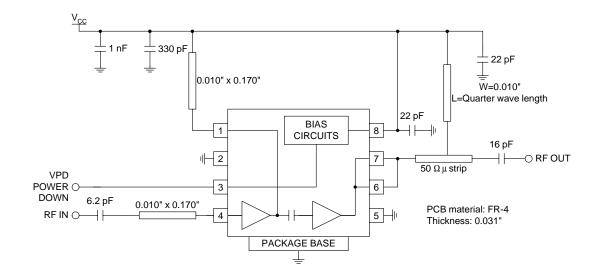
Dozomotor	Specification		11!4	0		
Parameter	Min.	Тур.	Max.	Unit	Condition	
Overall					T=25 °C, $V_{CC}$ =5 V, $V_{PD}$ =5 V, $Z_{LOAD}$ =106 Ω, $P_{IN}$ =-3dBm, Freq=1800 MHz	
Frequency Range		1500 to 1900		MHz		
Maximum Output Power		+20		dBm	V <sub>CC</sub> =5V, Pin=-3dBm	
Maximum Output Power		+23		dBm	V <sub>CC</sub> =6V, Pin=0dBm	
Total CW Efficiency		30		%	Maximum output, V <sub>CC</sub> =V <sub>PD</sub> =5V	
Small-signal Gain	23	25		dB		
Second Harmonic		-25		dBc	P <sub>OUT</sub> =20dBm	
Third Harmonic		-22		dBc	P <sub>OUT</sub> =20dBm	
Input VSWR		2:1				
Input Impedance		50		Ω		
Noise Figure		7		dB		
Two-Tone Specification						
Average Two-Tone Power		+17		dBm	PEP-3dB	
IM <sub>3</sub>		-40		dBc	P <sub>OUT</sub> =+14dBM for each tone	
IM <sub>5</sub>		-45		dBc	P <sub>OUT</sub> =+14dBM for each tone	
IM <sub>7</sub>		-44		dBc	P <sub>OUT</sub> =+14dBM for each tone	
Two-Tone Power-Added Efficiency		36		%		
Power Control						
Power Down "ON"		V <sub>CC</sub>		V	Voltage supplied to the input; Part is "ON"	
Power Down "OFF"	0		1.2	V	Voltage supplied to the input; Part is "OFF"	
Power Supply						
Voltage		5		V	Specifications	
		3.0 to 6.5		V	Operating Limits	
Current		50	65	mA	Operating Idle	
		80		mA	Maximum output	
			10	μΑ	Power Down	

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Pin	Function	Description	Interface Schematic
1	VCC2	Power supply for the driver stage and interstage matching. Matching is typically done by a microstrip line to $V_{CC}$ that is RF grounded at the $V_{CC}$ side. See the application information for details.	
2	GND1	Ground connection for the driver stage. Keep traces physically short and connect immediately to the ground plane for best performance. This connection should be separated from the ground connection for the output stage, i.e., using separate traces and vias.	
3	PD	Power Down control. When this pin is "low", all circuits are shut off. A "low" is typically 1.2 V or less at room temperature. When this pin is "high", all circuits are operating normally. A "high" is $V_{CC}$ . If $V_{PD}$ is below $V_{CC}$ , output power and performance will be degraded. This could be used to obtain some gain control, but results are not guaranteed.	
4	RF IN	RF Input. This is a $50\Omega$ input, but the actual impedance depends on the matching provided on pin 1. An external DC blocking capacitor is required if this port is connected to a DC path to ground.	
5	GND2	Ground connection for the output stage. Keep traces physically short and connect immediately to the ground plane for best performance. This connection should be separated from the ground connection for the driver stage, i.e., using separate traces and vias.	
6	RF OUT	RF Output and power supply for the output stage. Bias for the output stage needs to be provided on this pin. This can be done through a quarter-wave microstrip that is RF grounded on the other end. For matching to $50\Omega$ , an external series microstrip line is required.	
7	RF OUT	Same as pin 6.	
8	VCC1	Power supply for the bias circuits. An external RF bypass capacitor of 22 pF is required. Keep the traces to the capacitor as short as possible, and connect the capacitor immediately to the ground plane.	

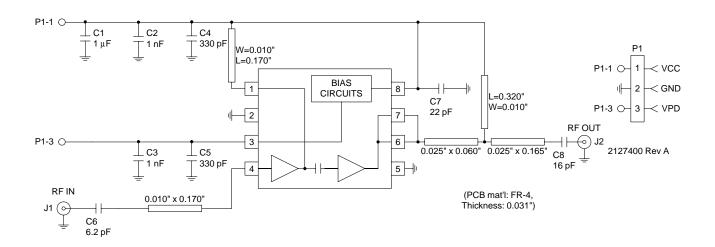
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## **Application Schematic** 1850MHz



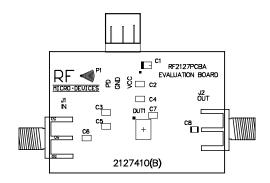
### **Evaluation Board Schematic**

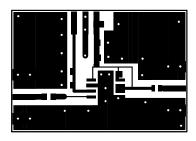
(Download Bill of Materials from www.rfmd.com.)

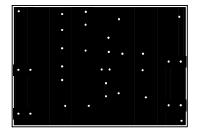


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# Evaluation Board Layout Board Size 1.55" x 1.07"







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